
	<h2>SIR422DP-T1-GE3</h2>
	<p>Hersteller-Teilenummer: SIR422DP-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 40V 40A PPAK SO-8</p> <p>Datenblätter:  SIR422DP-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 43040 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SIR422DP-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 40V 40A PPAK SO-8
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	43040 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	PowerPAK® SO-8
Supplier Device-Gehäuse	PowerPAK® SO-8
Verlustleistung (max)	5W (Ta), 34.7W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	40V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	40A (Tc)
Rds On (Max) @ Id, Vgs	6.6 mOhm @ 20A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	48nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1785pF @ 20V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)



















































SIR422DP-T1-GE3 ist neu im Original, Suche SIR422DP-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SIR422DP-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SIR422DP-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 SIR422DP VISHAY VISHAY QFN8	 SIR424DP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 20V 30A PPAK SO-8	 SIR424DP-T1-GE3 Vishay / Siliconix MOSFET N-CH 20V 30A PPAK SO-8	 SIR426DP-T1-GE3 Vishay / Siliconix MOSFET N-CH 40V 30A PPAK SO-8
 SIR422DP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 40V 40A PPAK SO-8	 SIR42-21C/TR8 EVERLIG EVERLIG 42-21	 SIR418DP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 40V 40A PPAK SO-8	 SIR424DP-T1-E3 VISHAY SIR424DP-T1-E3 VISHAY

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Mehr

 SIR406DP-T1-E3	 SIR406DP-T1-GE3	 SIR406DP-T1-GE3	 SIR406DP-T1-GE3-S	 SIR408DP-T1-GE3
 SIR408DP-T1-GE3	 SIR410DP-T1-E3	 SIR410DP-T1-GE3	 SIR410DP-T1-GE3	 SIR412DP
 SIR412DP-T1-E3	 SIR412DP-T1-GE3	 SIR412DP-T1-GE3	 SIR414DP	 SIR414DP-T1-GE3
 SIR414DP-T1-GE3	 SIR416DP	 SIR416DP-T1-E3	 SIR416DP-T1-GE3	 SIR416DP-T1-GE3
 SIR418DP-T1-E3	 SIR418DP-T1-GE3	 SIR418DP-T1-GE3	 SIR422DP-T1-E3	 SIR422DP-T1-GE3
 SIR424DP-T1-GE3	 SIR424DP-T1-GE3	 SIR426DP-T1-GE3	 SIR426DP-T1-GE3	 SIR428DP
 SIR428DP-T1-E3	 SIR428DP-T1-GE3	 SIR432DP-T1-GE3	 SIR432DP-T1-GE3	 SIR436DP-T1-E3
 SIR436DP-T1-GE3	 SIR436DP-T1-GE3	 SIR438DP	 SIR438DP-T1-GE3	 SIR438DP-T1-GE3
 SIR440DP-T1-GE3	 SIR440DP-T1-GE3	 SIR460DP	 SIR460DP-T1-E3	 SIR460DP-T1-GE3
 SIR460DP-T1-GE3	 SIR462DP	 SIR462DP-T1-E3	 SIR462DP-T1-GE3	 SIR462DP-T1-GE3

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